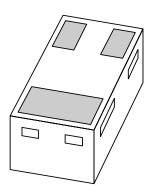
DISCRETE SEMICONDUCTORS

DATA SHEET



BAT54CMSchottky barrier double diode

Product specification

2003 Nov 11





Schottky barrier double diode

BAT54CM

FEATURES

- · Low forward voltage
- Leadless ultra small plastic package $(1.0 \times 0.6 \times 0.5 \text{ mm})$
- Boardspace 1.17 mm² (approx. 10% of SOT23)
- Power dissipation comparable to SOT23.

APPLICATIONS

- Ultra high-speed switching
- Voltage clamping
- · Protection circuits
- Mobile communications, digital (still) cameras, PDAs and PCMCIA cards.

DESCRIPTION

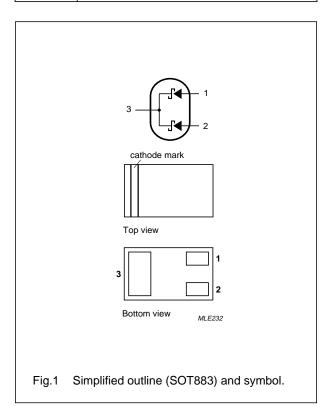
Planar Schottky barrier double diode encapsulated in a SOT883 leadless ultra small plastic package.

MARKING

TYPE NUMBER	MARKING CODE
BAT54CM	S3

PINNING

PIN	DESCRIPTION	
1	anode (a ₁)	
2	anode (a ₂)	
3	common cathode	



ORDERING INFORMATION

TYPE NUMBER PAC		PACKAGE	
TIPE NOMBER	NAME DESCRIPTION		VERSION
BAT54CM	_	leadless ultra small plastic package; 3 solder lands; SOT88 body $1.0 \times 0.6 \times 0.5$ mm	

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Schottky barrier double diode

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LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _R	continuous reverse voltage		_	30	V
I _F	continuous forward current		_	200	mA
I _{FRM}	repetitive peak forward current	$t_p \le 1 \text{ s}; \ \delta \le 0.5$	_	300	mA
I _{FSM}	non-repetitive peak forward current	t _p < 10 ms	_	600	mA
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C
P _{tot}	total power dissipation (per package)	T _{amb} ≤ 25 °C; note 1	_	250	mW

Note

1. Refer to SOT883 standard mounting conditions (footprint); FR4 with 60 μm copper strip line.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-a}	thermal resistance from junction to ambient	note 1	500	K/W

Note

1. Refer to SOT883 standard mounting conditions (footprint), FR4 with 60 μm copper strip line.

Soldering

Reflow soldering is the only recommended soldering method.

ELECTRICAL CHARACTERISTICS

 T_{amb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MAX.	UNIT	
Per diode					
V _F	forward voltage	see Fig.2;			
		$I_F = 0.1 \text{ mA}$	240	mV	
		$I_F = 1 \text{ mA}$	320	mV	
		I _F = 10 mA	400	mV	
		I _F = 30 mA	500	mV	
		I _F = 100 mA	800	mV	
I _R	continuous reverse current	V _R = 25 V; note 1; see Fig.3	2	μΑ	
C _d	diode capacitance	$f = 1 \text{ MHz}; V_R = 1 \text{ V}; \text{ see Fig.4}$	10	pF	

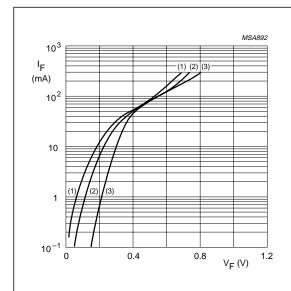
Note

1. Pulsed test: $t_p \le 300 \ \mu s$; $\delta \le 0.02$.

Product specification Philips Semiconductors

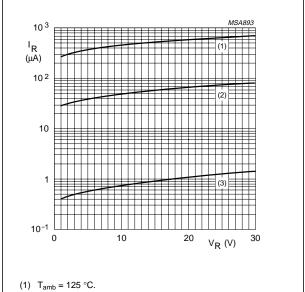
Schottky barrier double diode

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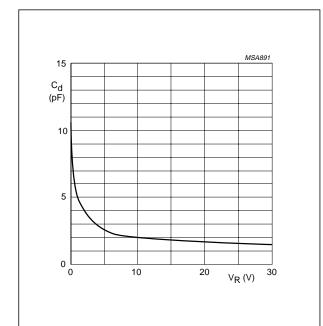
- (1) $T_{amb} = 125 \, ^{\circ}C$.
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.

Fig.2 Forward current as a function of forward voltage; typical values.



- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.

Fig.3 Reverse current as a function of reverse voltage; typical values.



f = 1 MHz; $T_{amb} = 25$ °C.

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Diode capacitance as a function of reverse voltage; typical values.

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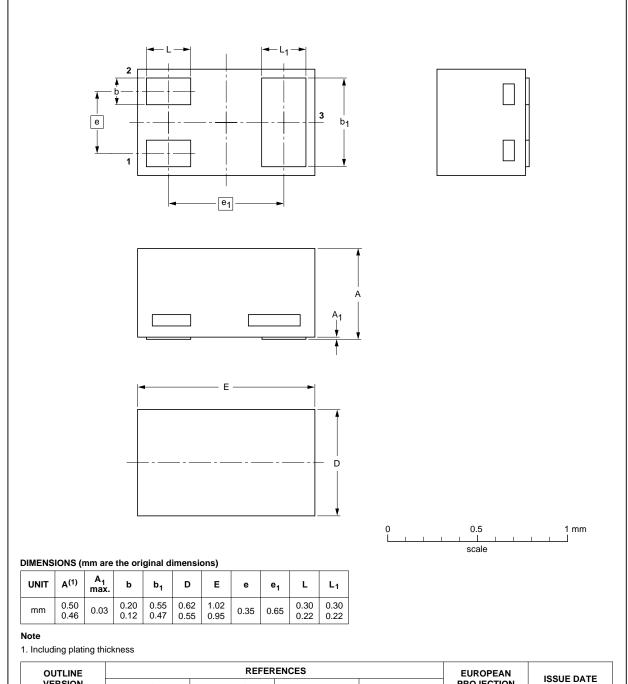
Schottky barrier double diode

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PACKAGE OUTLINE

Leadless ultra small plastic package; 3 solder lands; body 1.0 x 0.6 x 0.5 mm

SOT883



OUTLINE	REFERENCES			EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT883			SC-101			03-02-05 03-04-03

Philips Semiconductors Product specification

Schottky barrier double diode

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DATA SHEET STATUS

LEVEL	DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾⁽³⁾	DEFINITION
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
II	Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
III	Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN).

Notes

- 1. Please consult the most recently issued data sheet before initiating or completing a design.
- 2. The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.
- 3. For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

DEFINITIONS

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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